

Rectifier diodes ultrafast, rugged

BYV42E series

GENERAL DESCRIPTION

Glass passivated high efficiency rugged dual rectifier diodes in a plastic envelope, featuring low forward voltage drop, ultra-fast recovery times and soft recovery characteristic. These devices can withstand reverse voltage transients and have guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

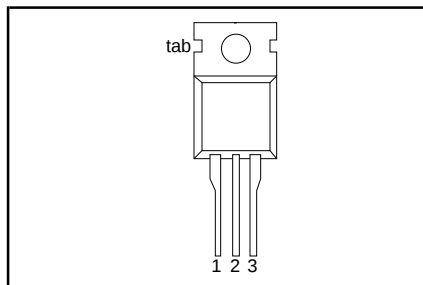
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V_{RRM}	BYV42E- Repetitive peak reverse voltage	100 100	150 150	200 200	V
V_F	Forward voltage	0.85	0.85	0.85	V
$I_{O(AV)}$	Output current (both diodes conducting)	30	30	30	A
t_{rr}	Reverse recovery time	28	28	28	ns
I_{RRM}	Repetitive peak reverse current per diode	0.2	0.2	0.2	A

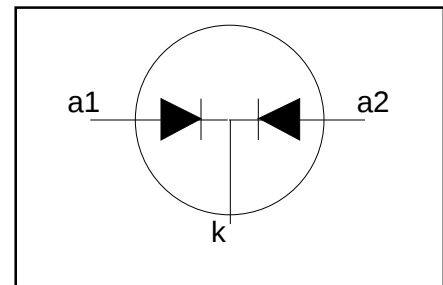
PINNING - TO220AB

PIN	DESCRIPTION
1	anode 1 (a)
2	cathode (k)
3	anode 2 (a)
tab	cathode (k)

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
V_{RRM}	Repetitive peak reverse voltage		-	-100	-150	-200	V
V_{RWM}	Crest working reverse voltage		-	100	150	200	V
V_R	Continuous reverse voltage ¹		-	100	150	200	V
$I_{O(AV)}$	Output current (both diodes conducting) ²	square wave $\delta = 0.5$; $T_{mb} \leq 108^\circ\text{C}$ sinusoidal $a = 1.57$; $T_{mb} \leq 111^\circ\text{C}$	-	30			A
$I_{O(RMS)}$	RMS forward current		-	43			A
I_{FRM}	Repetitive peak forward current per diode	$t = 25\ \mu\text{s}$; $\delta = 0.5$; $T_{mb} \leq 108^\circ\text{C}$	-	30			A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10\ \text{ms}$ $t = 8.3\ \text{ms}$ sinusoidal; with reappplied	-	150			A
I^2t	I^2t for fusing	$V_{RWM(max)}$ $t = 10\ \text{ms}$	-	112			A ² s
I_{RRM}	Repetitive peak reverse current per diode	$t_p = 2\ \mu\text{s}$; $\delta = 0.001$	-	0.2			A
I_{RSM}	Non-repetitive peak reverse current per diode	$t_p = 100\ \mu\text{s}$	-	0.2			A
T_{stg}	Storage temperature		-40	150			$^\circ\text{C}$
T_j	Operating junction temperature		-	150			$^\circ\text{C}$

1 $T_{mb} \leq 144^\circ\text{C}$ for thermal stability.

2 Neglecting switching and reverse current losses.

For output currents in excess of 20 A, connection should be made to the exposed metal mounting base.

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_C	Electrostatic discharge capacitor voltage	Human body model; $C = 250 \text{ pF}$; $R = 1.5 \text{ k}\Omega$	-	8	kV

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-mb}$	Thermal resistance junction to mounting base	per diode	-	-	2.4	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	both diodes conducting in free air	-	-	1.4	K/W
			-	60	-	K/W

STATIC CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage (per diode)	$I_F = 15 \text{ A}$; $T_j = 150^\circ\text{C}$	-	0.78	0.85	V
		$I_F = 15 \text{ A}$	-	0.95	1.05	V
		$I_F = 30 \text{ A}$	-	1.00	1.20	V
I_R	Reverse current (per diode)	$V_R = V_{RWM}$; $T_j = 100^\circ\text{C}$	-	0.5	1	mA
		$V_R = V_{RWM}$	-	10	100	μA

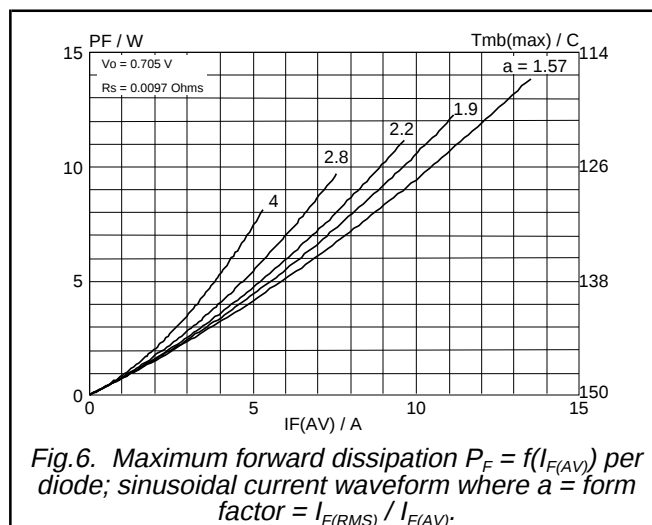
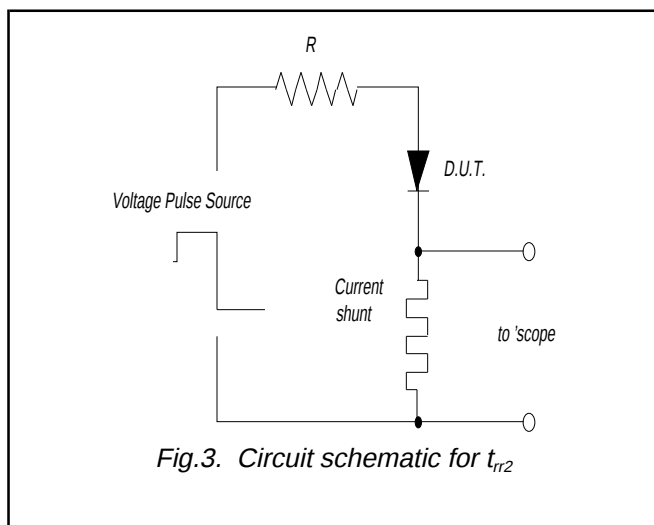
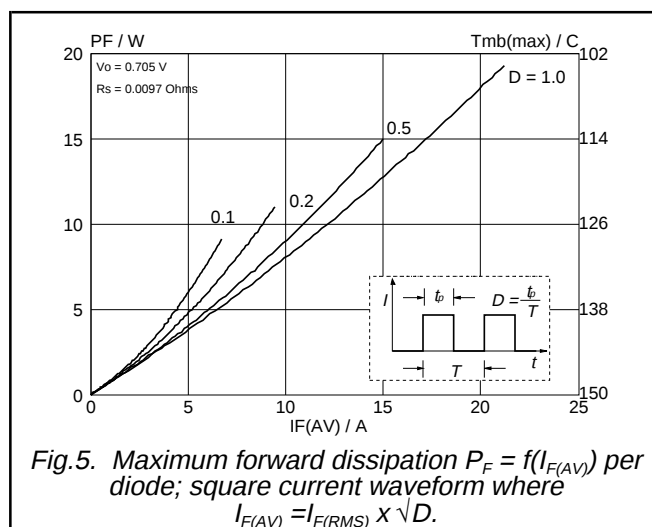
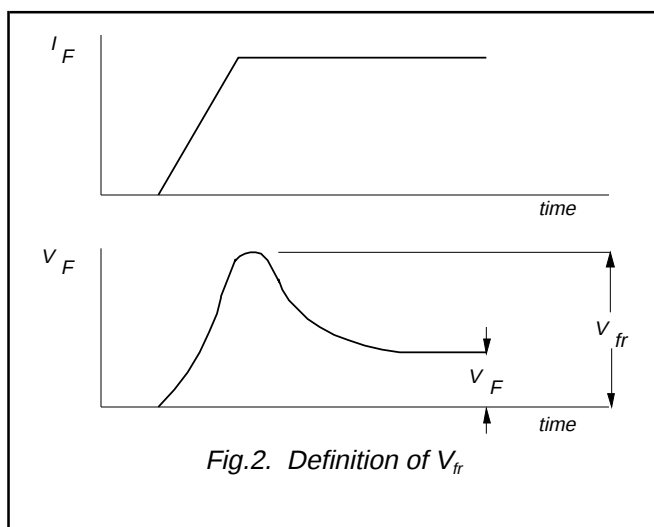
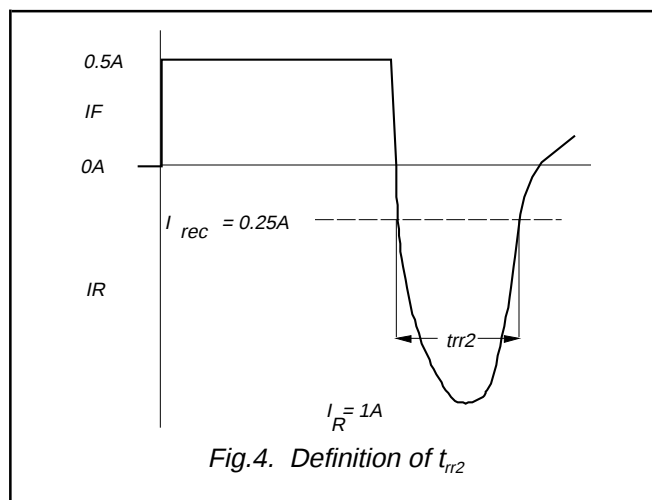
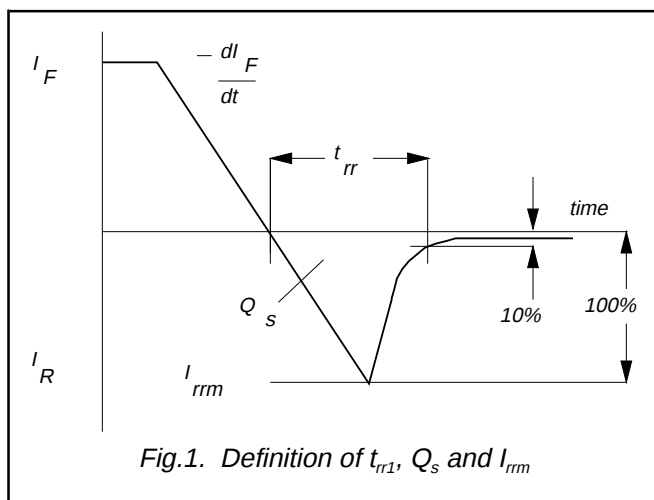
DYNAMIC CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q_s	Reverse recovery charge (per diode)	$I_F = 2 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 20 \text{ A}/\mu\text{s}$	-	6	15	nC
t_{rr1}	Reverse recovery time (per diode)	$I_F = 1 \text{ A}$; $V_R \geq 30 \text{ V}$; $-di_F/dt = 100 \text{ A}/\mu\text{s}$	-	20	28	ns
t_{rr2}	Reverse recovery time (per diode)	$I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$; $I_{rec} = 0.25 \text{ A}$	-	13	22	ns
V_{fr}	Forward recovery voltage (per diode)	$I_F = 1 \text{ A}$; $di_F/dt = 10 \text{ A}/\mu\text{s}$	-	1	-	V

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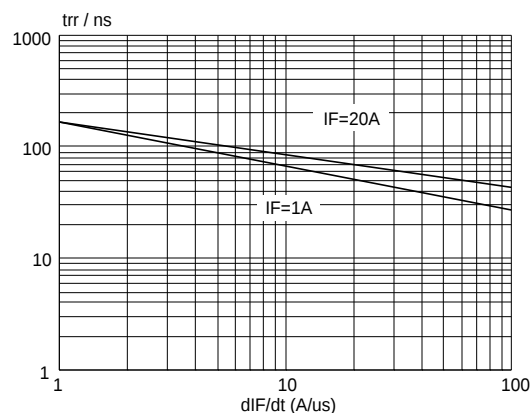


Fig. 7. Maximum t_{rr} at $T_j = 25\text{ }^{\circ}\text{C}$; per diode

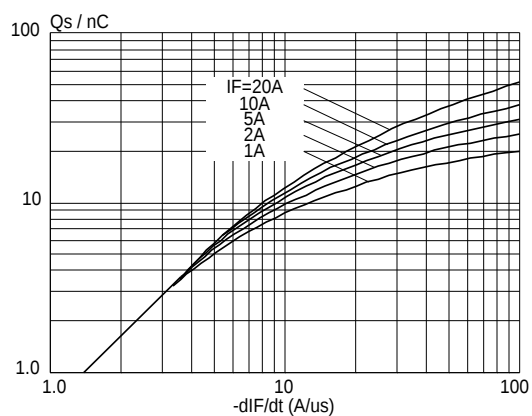


Fig. 10. Maximum Q_s at $T_j = 25\text{ }^{\circ}\text{C}$; per diode

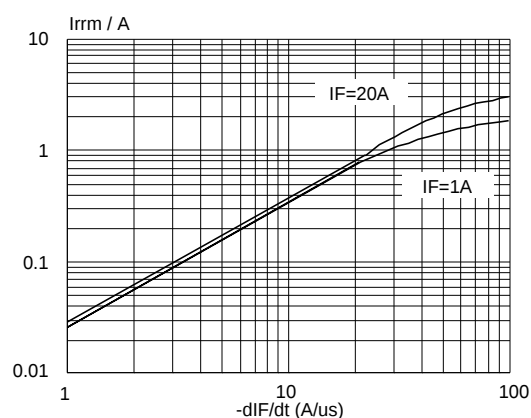


Fig. 8. Maximum I_{rrm} at $T_j = 25\text{ }^{\circ}\text{C}$; per diode

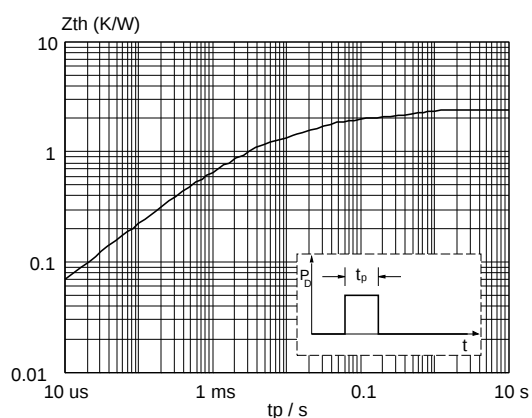


Fig. 11. Transient thermal impedance; per diode;
 $Z_{th\ j-mb} = f(t_p)$.

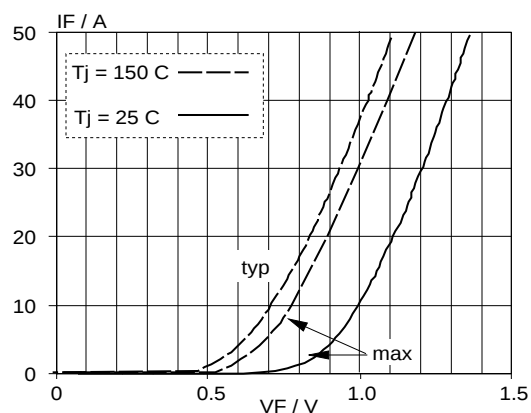


Fig. 9. Typical and maximum forward characteristic
 $I_F = f(V_F)$; parameter T_j

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MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

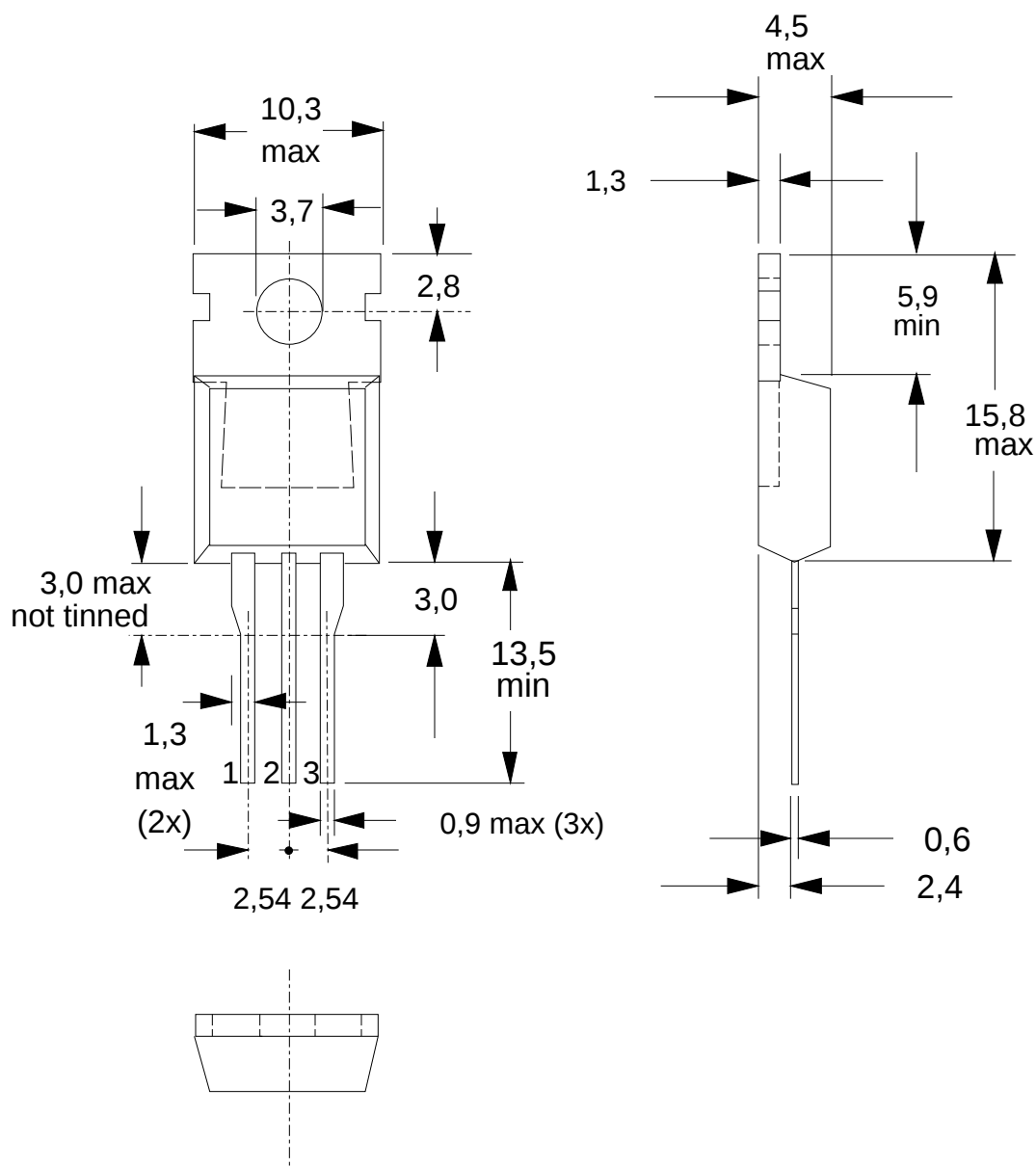


Fig.12. TO220AB; pin 2 connected to mounting base.

Notes

1. Accessories supplied on request: refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	
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